







	<h2>IRFBC30ASPBF</h2>
	<p>Hersteller-Teilenummer: IRFBC30ASPBF</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 3.6A D2PAK</p> <p>Datenblätter:  IRFBC30ASPBF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 5000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IRFBC30ASPBF
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 600V 3.6A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	5000 pcs Stock
Hersteller Standard Vorlaufzeit	18 Weeks
detaillierte Beschreibung	N-Channel 600V 3.6A (Tc) 74W (Tc) Surface Mount
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	74W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.6A (Tc)
Rds On (Max) @ Id, Vgs	2.2 Ohm @ 2.2A, 10V
VGS (th) (Max) @ Id	4.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	510pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	*IRFBC30ASPBF










IRFBC30ASPBF ist neu im Original, Suche IRFBC30ASPBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFBC30ASPBF Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage IRFBC30ASPBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IRFBC30AS Electro-Films (EFI) / Vishay MOSFET N-CH 600V 3.6A D2PAK</p>	 <p>IRFBC30ASTRL Vishay / Siliconix MOSFET N-CH 600V 3.6A D2PAK</p>	 <p>IRFBC30AS Vishay / Siliconix MOSFET N-CH 600V 3.6A D2PAK</p>	 <p>IRFBC30ASTRLPBF Electro-Films (EFI) / Vishay MOSFET N-CH 600V 3.6A D2PAK</p>
 <p>IRFBC30ASPBF Vishay / Siliconix MOSFET N-CH 600V 3.6A D2PAK</p>	 <p>IRFBC30APBF Vishay / Siliconix MOSFET N-CH 600V 3.6A TO-220AB</p>	 <p>IRFBC30APBF Electro-Films (EFI) / Vishay MOSFET N-CH 600V 3.6A TO-220AB</p>	 <p>IRFBC30ASTRLPBF Vishay / Siliconix MOSFET N-CH 600V 3.6A D2PAK</p>

heiße Teile

Mehr

 IRFB9N65A	 IRFB9N65A	 IRFB9N65APBF	 IRFB9N65APBF	 IRFBA1404P
 IRFBA1404PPBF	 IRFBA1405P	 IRFBA22N50A	 IRFBC20-030	 IRFBC20LPBF
 IRFBC20LPBF	 IRFBC20PBF	 IRFBC20PBF	 IRFBC20SPBF	 IRFBC20SPBF
 IRFBC20STRL	 IRFBC20STRL	 IRFBC20STRLPBF	 IRFBC20STRLPBF	 IRFBC20STRR
 IRFBC20STRR	 IRFBC30ALPBF	 IRFBC30ALPBF	 IRFBC30AS	 IRFBC30AS
 IRFBC30ASPBF	 IRFBC30ASTRL	 IRFBC30ASTRL	 IRFBC30ASTRR	 IRFBC30ASTRR
 IRFBC30ASTRRPBF	 IRFBC30ASTRRPBF	 IRFBC30LPBF	 IRFBC30LPBF	 IRFBC30LTRR
 IRFBC30PBF	 IRFBC30PBF	 IRFBC30S	 IRFBC30S	 IRFBC30STRLPBF
 IRFBC30STRLPBF	 IRFBC30STRR	 IRFBC30STRR	 IRFBC40A	 IRFBC40A
 IRFBC40APBF	 IRFBC40APBF	 IRFBC40AS	 IRFBC40AS	 IRFBC40ASPBF

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited

